Product Specification

PE43703

50 Ω RF Digital Attenuator
7-bit, 31.75 dB, 9 kHz - 6000 MHz
Vss_{EXT} option

Features

- HaRP™-enhanced UltraCMOS™ device
- Attenuation options: 0.25 dB, 0.5 dB, or 1.0 dB steps to 31.75 dB
  - 0.25 dB monotonicity for ≤4.0 GHz
  - 0.5 dB monotonicity for ≤5.0 GHz
  - 1 dB monotonicity for ≤6.0 GHz
- High Linearity: Typical +59 dBm IIP3
  - Excellent low-frequency performance
- Optional External Vss Control (Vss_{EXT})
- 3.3 V or 5.0 V Power Supply Voltage
- Fast switch settling time
- Programming Modes:
  - Direct Parallel
  - Latched Parallel
  - Serial-Addressable: Program up to eight addresses 000 - 111
- High-attenuation state @ power-up (PUP)
- CMOS Compatible
- No DC blocking capacitors required

Product Description

The PE43703 is a HaRP™-enhanced, high linearity, 7-bit RF Digital Step Attenuator (DSA). This highly versatile DSA covers a 31.75 dB attenuation range in 0.25 dB, 0.5 dB, or 1.0 dB steps. The customer can choose which step size and associated specifications are best suited for their application. The Peregrine 50Ω RF DSA provides multiple CMOS control interfaces and an optional external Vss feature. It maintains high attenuation accuracy over frequency and temperature and exhibits very low insertion loss and low power consumption. Performance does not change with V_{DD} due to on-board regulator. This next generation Peregrine DSA is available in a 5x5 mm 32-lead QFN footprint.

The PE43703 is manufactured on Peregrine's UltraCMOS™ process, a patented variation of silicon-on-insulator (SOI) technology on a sapphire substrate, offering the performance of GaAs with the economy and integration of conventional CMOS.

Figure 1. Package Type

32-lead 5x5x0.85 mm QFN Package

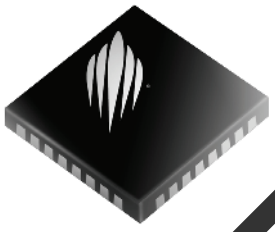


Figure 2. Functional Schematic Diagram

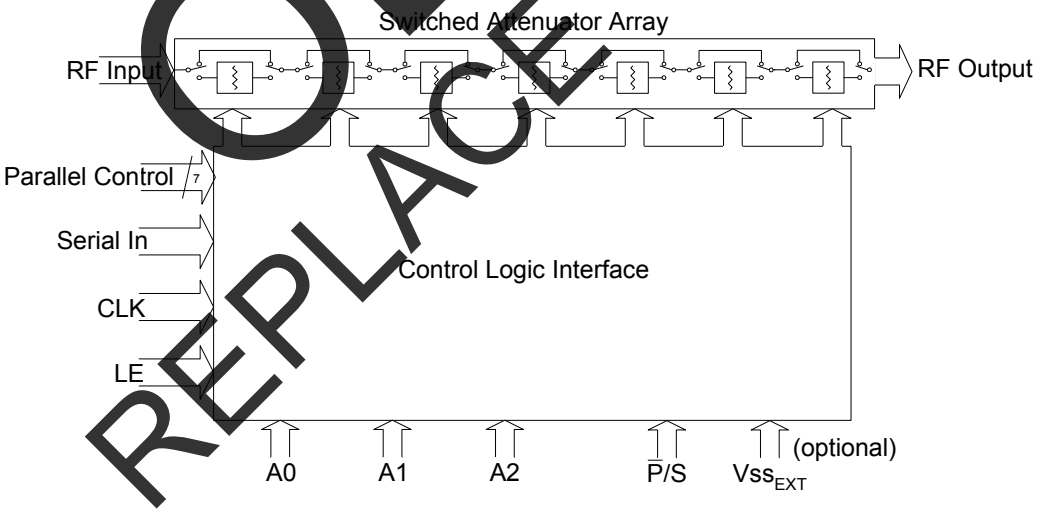


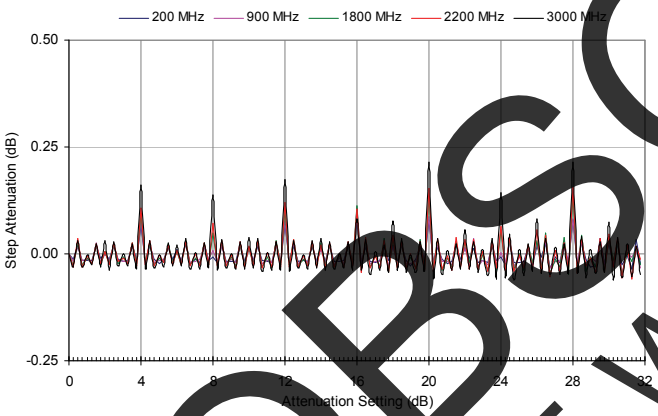
Table 1. Electrical Specifications: 0.25 dB steps @ +25°C, V_{DD} = 3.3 V or 5.0 V, Vss_{EXT} = -2.7 V or GND

Parameter	Test Conditions	Frequency	Min	Typical	Max	Units
Frequency Range			9 kHz		4000 MHz	
Attenuation Range	0.25 dB Step			0 – 31.75		dB
Insertion Loss		9 kHz ≤ 4 GHz		1.9	2.4	dB
Attenuation Error	0 dB - 7.75 dB Attenuation settings 8 dB - 31.75 dB Attenuation settings 0 dB - 31.75 dB Attenuation settings	9 kHz < 3 GHz 9 kHz < 3 GHz 3 GHz < 4 GHz			±(0.2+1.5%) ±(0.15+4%) ±(0.25+4.5%)	dB dB dB
Return Loss		9 kHz - 4 GHz		18		dB
Relative Phase	All States	9 kHz - 4 GHz		33		deg
P1dB (note 1)	Input	20 MHz - 4 GHz	30	32		dBm
IIP3	Two tones at +18 dBm, 20 MHz spacing	20 MHz - 4 GHz		59		dBm
Typical Spurious Value[2]	Vss_{EXT} grounded	1 MHz		-110		dBm
Video Feed Through				10		mVpp
Switching Time	50% DC CTRL to 10% / 90% RF			650		ns
RF Trise/Tfall	10% / 90% RF			400		ns
Settling Time	RF settled to within 0.05 dB of final value. RBW = 5 MHz, Averaging ON.			4	25	µs

Notes: 1. Please note Maximum Operating Pin (50Ω) of +23dBm as shown in Table 5.
2. To prevent negative voltage generator spurs, supply –2.7 volts to Vss_{EXT}.

Performance Plots, 0.25 dB step

Figure 3. 0.25 dB Step Attenuation*



*Monotonicity is held so long as Step-Attenuation does not cross below -0.25

Figure 4. 0.25 dB Step, Actual vs. Ideal Attenuation

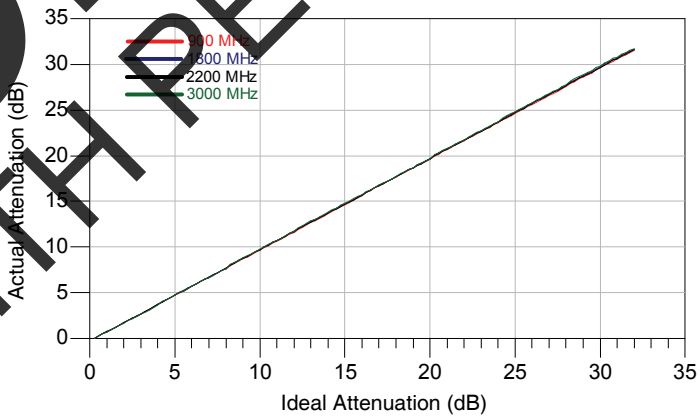


Figure 5. 0.25 dB Major State Bit Error

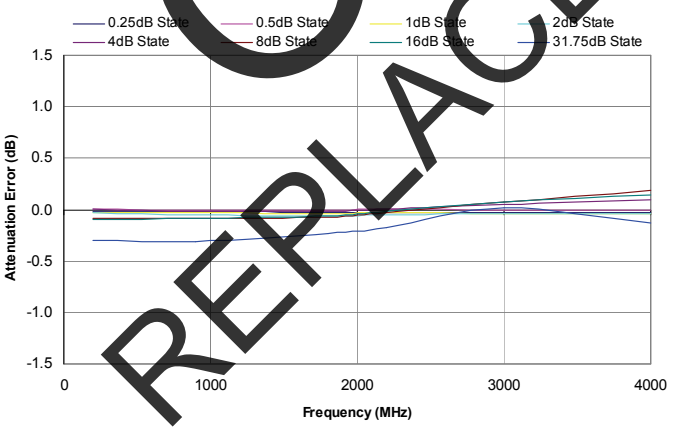


Figure 6. 0.25 dB Attenuation Error

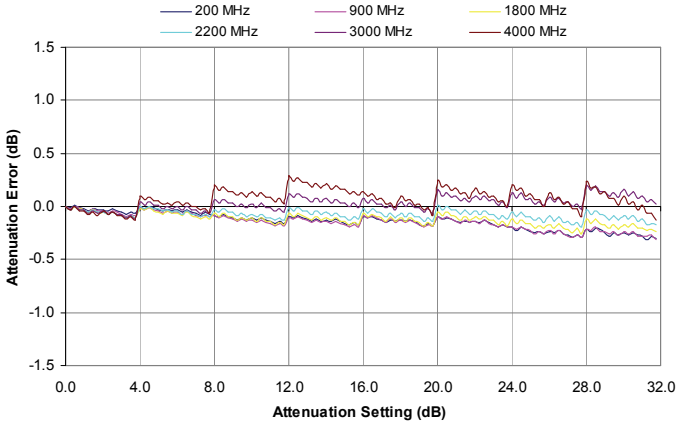


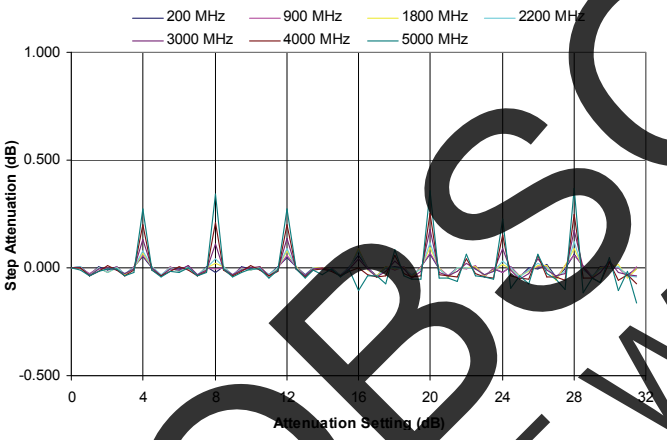
Table 2. Electrical Specifications: 0.5 dB steps @ +25°C, V_{DD} = 3.3 V or 5.0 V, Vss_{EXT} = -2.7 V or GND

Parameter	Test Conditions	Frequency	Min	Typical	Max	Units
Frequency Range			9 kHz		5000 MHz	
Attenuation Range	0.5 dB Step			0 – 31.5		dB
Insertion Loss		9 kHz ≤5 GHz		2.0	2.6	dB
Attenuation Error	0 dB - 31.5 dB Attenuation settings 0 dB - 16.5 dB Attenuation settings 17 dB - 31.5 dB Attenuation settings	9 kHz < 4 GHz 4 ≤5 GHz 4 ≤5 GHz			±(0.25+4.5%) ±(0.3+5%) ±(1.3+0%)	dB dB dB
Return Loss		9 kHz - 5 GHz		18		dB
Relative Phase	All States	9 kHz - 5 GHz		56		deg
P1dB (note 1)	Input	20 MHz - 5 GHz	30	32		dBm
IIP3	Two tones at +18 dBm, 20 MHz spacing	20 MHz - 5 GHz		57		dBm
Typical Spurious Value[2]	Vss_{EXT} grounded	1 MHz		-110		dBm
Video Feed Through				10		mVpp
Switching Time	50% DC CTRL to 10% / 90% RF			650		ns
RF Trise/Tfall	10% / 90% RF			400		ns
Settling Time	RF settled to within 0.05 dB of final value. RBW = 5 MHz, Averaging ON.			4	25	µs

Notes: 1. Please note Maximum Operating Pin (50Ω) of +23dBm as shown in Table 5.
2. To prevent negative voltage generator spurs, supply –2.7 volts to Vss_{EXT}.

Performance Plots, 0.5 dB step

Figure 7. 0.5 dB Step Attenuation*



*Monotonicity is held so long as Step-Attenuation does not cross below -0.5

Figure 8. 0.5 dB Step, Actual vs. Ideal Attenuation

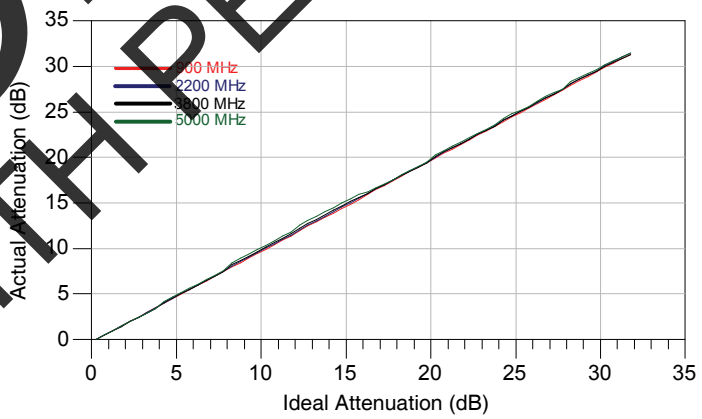


Figure 9. 0.5 dB Major State Bit Error

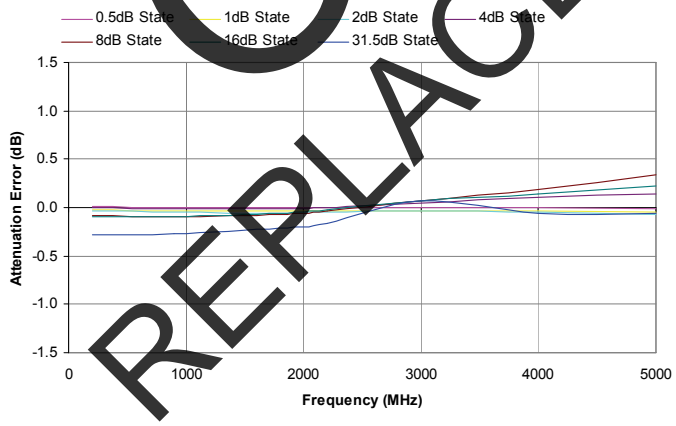


Figure 10. 0.5 dB Attenuation Error

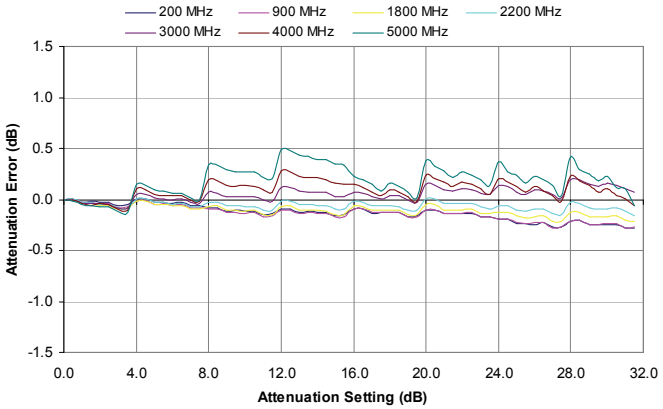


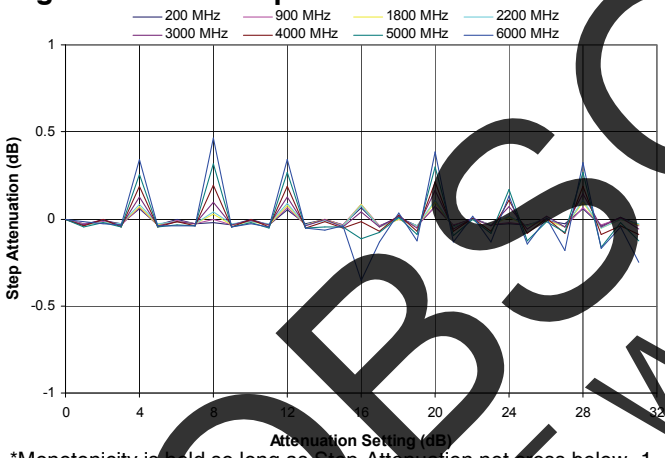
Table 3. Electrical Specifications: 1 dB steps @ +25°C, V_{DD} = 3.3 V or 5.0 V, Vss_{EXT} = -2.7 V or GND

Parameter	Test Conditions	Frequency	Min	Typical	Max	Units
Frequency range			9 kHz		6000 MHz	
Attenuation Range	1 dB Step			0 - 31		dB
Insertion Loss		9 kHz ≤6 GHz		2.3	2.8	dB
Attenuation Error	0 dB - 31 dB Attenuation settings 0 dB - 12 dB Attenuation settings 13 dB - 31 dB Attenuation setting 0 dB - 31 dB Attenuation settings	9 kHz – 4 GHz 4 GHz ≤6 GHz 4 GHz ≤6 GHz 4 GHz ≤6 GHz			±(0.25+4.5%) +0.4+8% +1.4+0% -0.2-3%	dB dB dB dB
Return Loss		9 kHz - 6 GHz		18		dB
Relative Phase	All States	9 kHz - 6 GHz		74		deg
P1dB (note 1)	Input	20 MHz - 6 GHz	30	32		dBm
IIP3	Two tones at +18 dBm, 20 MHz spacing	20 MHz - 6 GHz		53		dBm
Typical Spurious Value[2]	Vss_{EXT} grounded	1 MHz		-110		dBm
Video Feed Through				10		mVpp
Switching Time	50% DC CTRL to 10% / 90% RF			650		ns
RF Trise/Tfall	10% / 90% RF			400		ns
Settling Time	RF settled to within 0.05 dB of final value. RBW = 5 MHz, Averaging ON.			4	25	µs

Notes: 1. Please note Maximum Operating Pin (50Ω) of +23dBm as shown in Table 5.
2. To prevent negative voltage generator spurs, supply –2.7 volts to Vss_{EXT}.

Performance Plots, 1 dB step

Figure 11. 1 dB Step Attenuation



*Monotonicity is held so long as Step-Attenuation not cross below -1

Figure 12. 1 dB Step, Actual vs. Ideal Attenuation

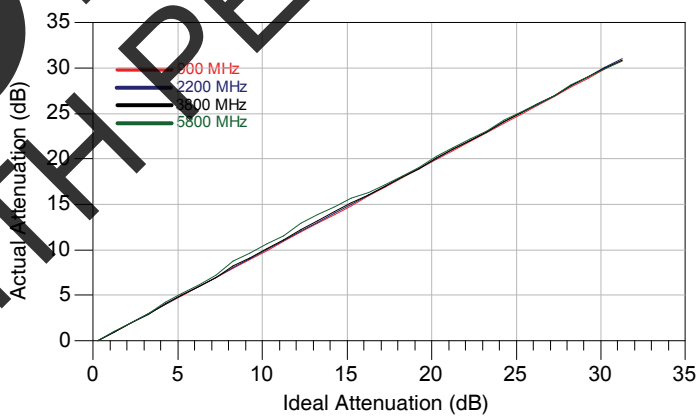


Figure 13. 1 dB Major State Bit Error

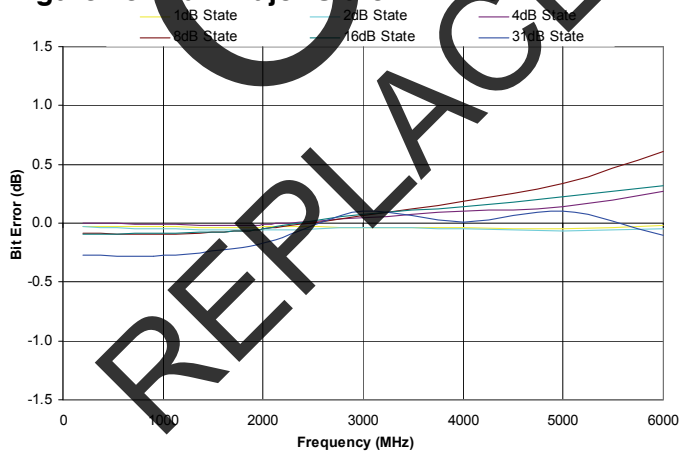
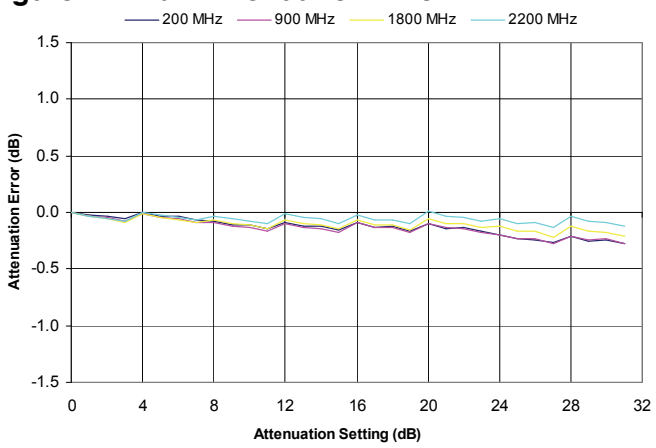


Figure 14. 1 dB Attenuation Error



Performance Plots, 1 dB step (continued)

Figure 15. 1 dB Attenuation Error (continued)

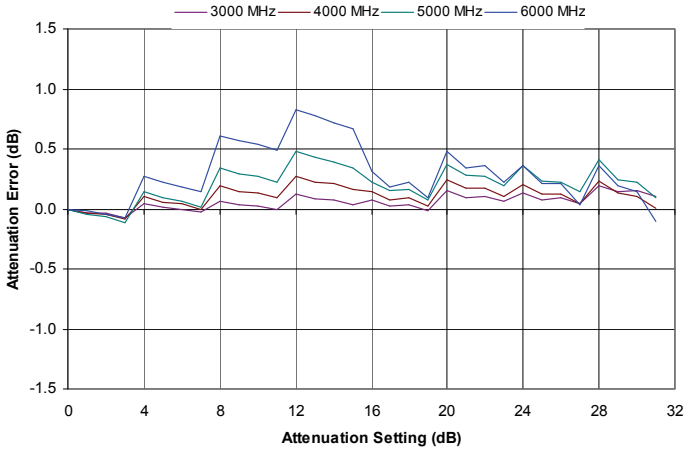


Figure 16. Insertion Loss @ Temperature

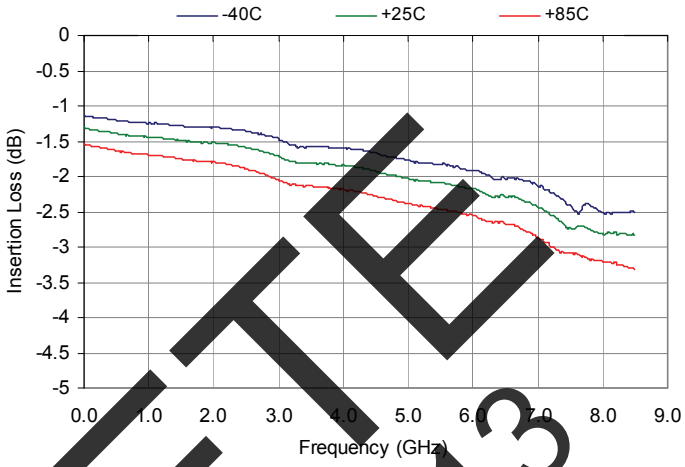


Figure 17. Input Return Loss (+25C)

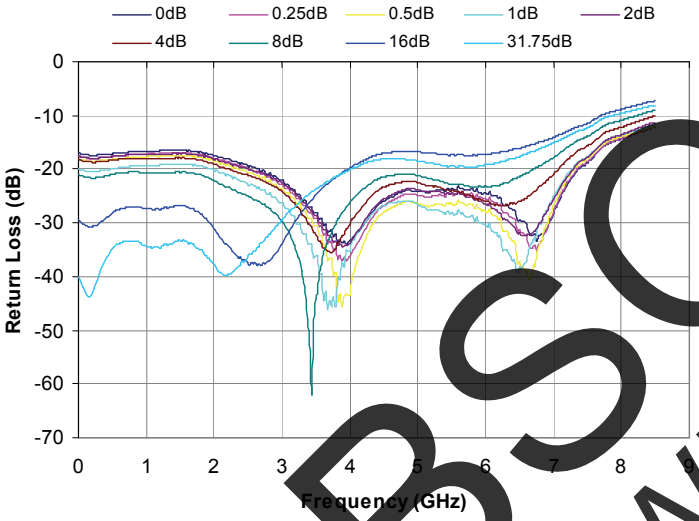


Figure 18. Output Return Loss (+25C)

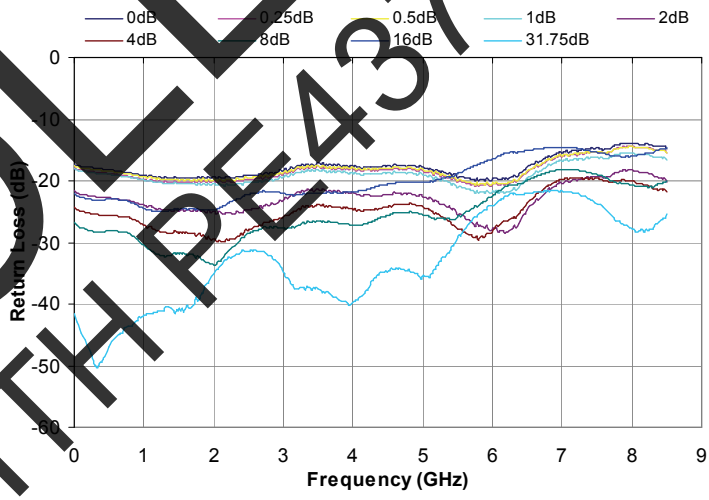


Figure 19. Input Return Loss @ Temperature for 16 dB State

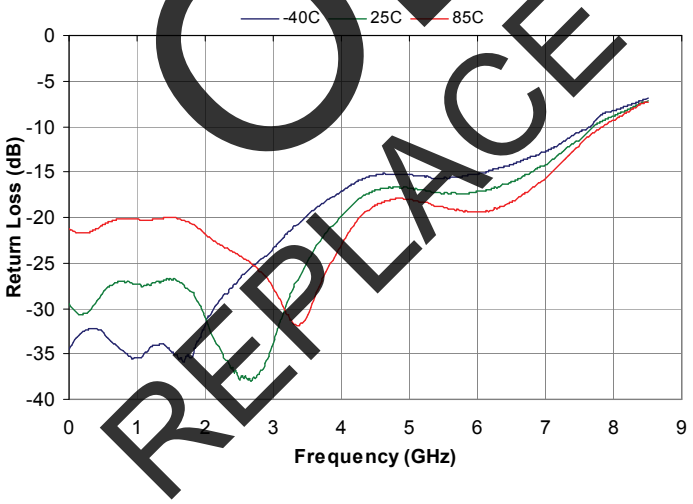
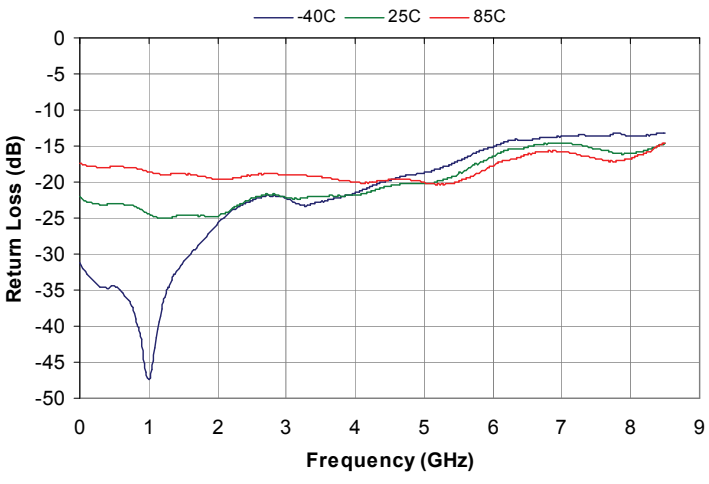


Figure 20. Output Return Loss @ Temperature for 16 dB State



Performance Plots (continued)

Figure 21. Relative Phase Error

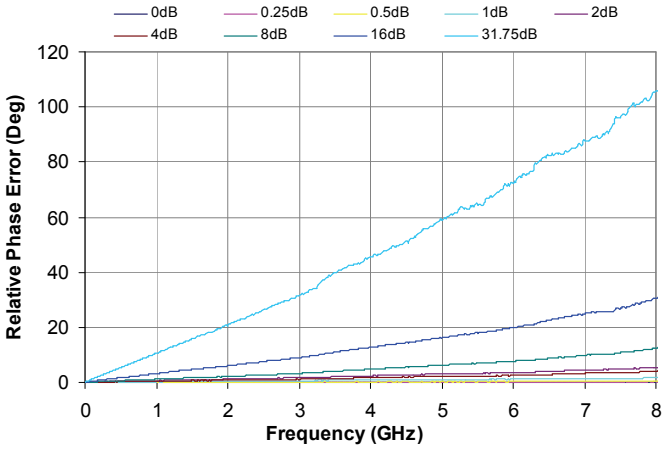


Figure 22. Relative Phase Error vs. Temperature for 31.75 dB State

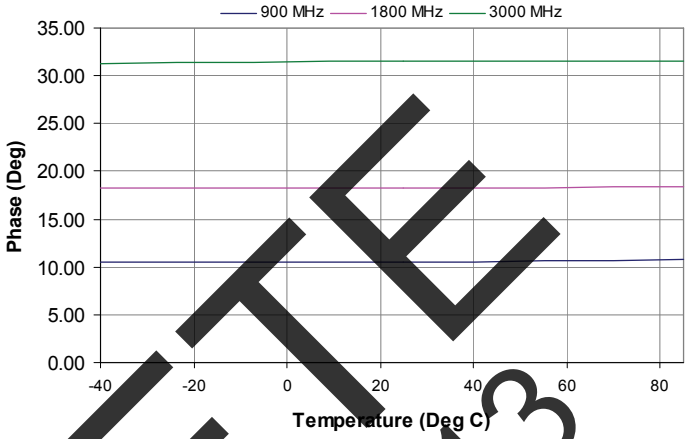


Figure 23. Attenuation Error @ 900 MHz

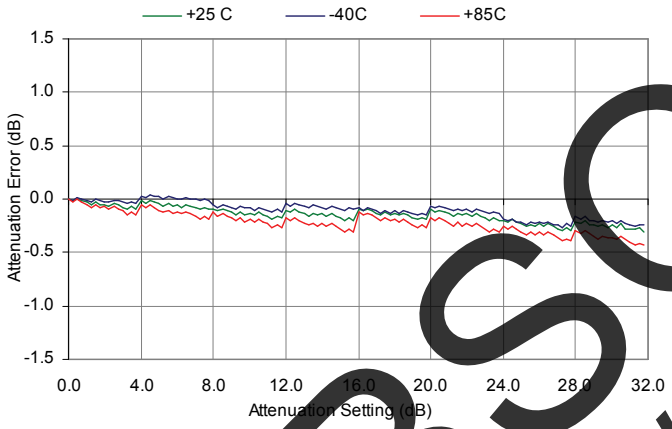


Figure 24. Attenuation Error @ 1800 MHz

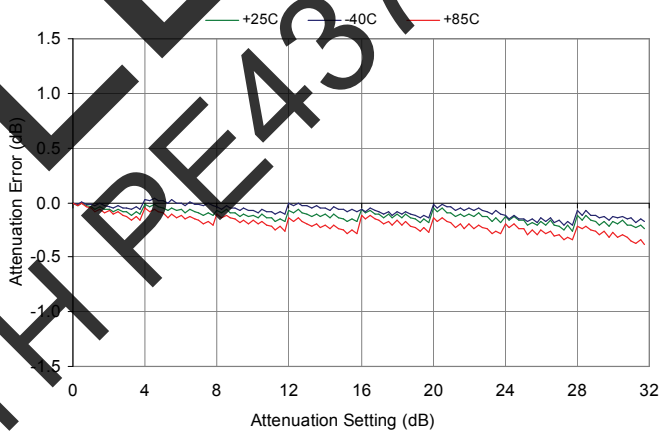


Figure 25. Attenuation Error @ 3000 MHz

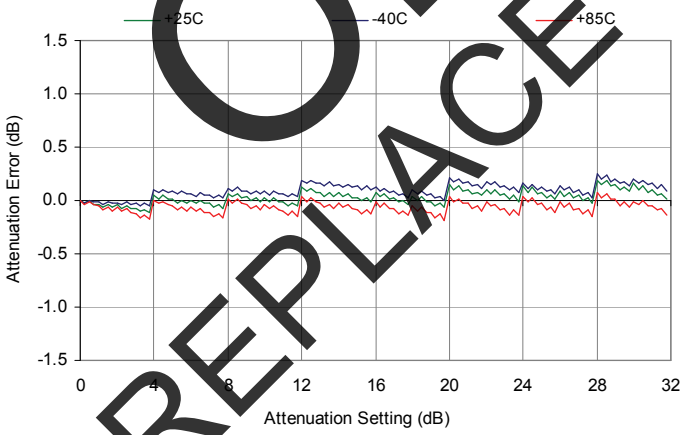


Figure 26. Input IP3 vs. Frequency

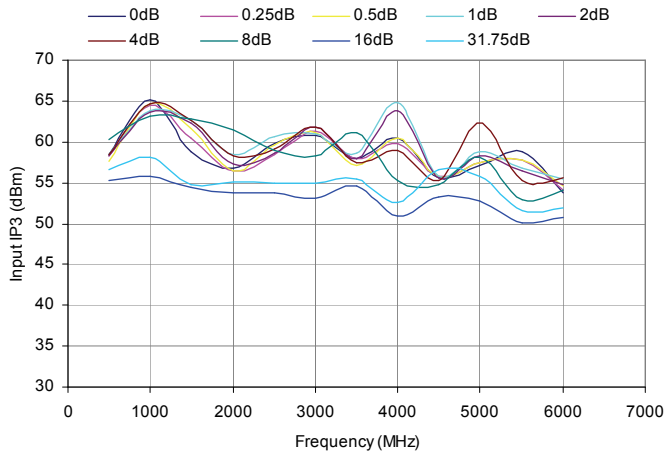


Figure 27. Pin Configuration (Top View)

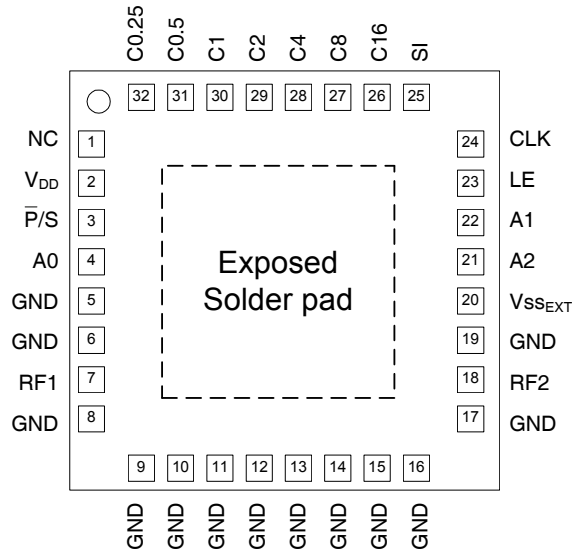


Table 4. Pin Descriptions

Pin No.	Pin Name	Description
1	N/C	No Connect
2	V_{DD}	Power supply pin
3	P/S	Serial/Parallel mode select
4	A0	Address Bit A0 connection
5	GND	Ground
6	GND	Ground
7	RF1	RF1 port
8 - 17	GND	Ground
18	RF2	RF2 port
19	GND	Ground
20	Vss_{EXT}	External Vss Control
21	A2	Address Bit A2 connection
22	A1	Address Bit A1 connection
23	LE	Serial interface Latch Enable input
24	CLK	Serial interface Clock input
25	SI	Serial interface Data input
26	C16 (D6)	Parallel control bit, 16 dB
27	C8 (D5)	Parallel control bit, 8 dB
28	C4 (D4)	Parallel control bit, 4 dB
29	C2 (D3)	Parallel control bit, 2 dB
30	C1 (D2)	Parallel control bit, 1 dB
31	C0.5 (D1)	Parallel control bit, 0.5 dB
32	C0.25 (D0)	Parallel control bit, 0.25 dB
Paddle	GND	Ground for proper operation

Note: Ground C0.25, C0.5, C1 C2, C4, C8, C16 if not in use.

Electrostatic Discharge (ESD) Precautions

When handling this UltraCMOS™ device, observe the same precautions that you would use with other ESD-sensitive devices. Although this device contains circuitry to protect it from damage due to ESD, precautions should be taken to avoid exceeding the specified rating.

Latch-Up Avoidance

Unlike conventional CMOS devices, UltraCMOS™ devices are immune to latch-up.

Optional External Vss Control (Vss_{EXT})

For proper operation, the Vss_{EXT} control must be grounded or at the Vss voltage specified in the Operating Ranges table. When the Vss_{EXT} control pin on the package is grounded the switch FET's are biased with an internal low spur negative voltage generator. For applications that require the lowest possible spur performance, Vss_{EXT} can be applied to bypass the internal negative voltage generator to eliminate the spurs.

Switching Frequency

The PE43703 has a maximum 25 kHz switching rate when Vss_{EXT} is grounded. Switching rate is defined to be the speed at which the DSA can be toggled across attenuation states.

Moisture Sensitivity Level

The Moisture Sensitivity Level rating for the PE43703 in the 5x5 QFN package is MSL1.

Exposed Solder Pad Connection

The exposed solder pad on the bottom of the package must be grounded for proper device operation.

Table 5. Operating Ranges

Parameter	Min	Typ	Max	Units
V_{DD} 3.3 V Power Supply Voltage	3.0	3.3	3.6	V
V_{DD} 5.0 V Power Supply Voltage	4.5	5.0	5.5	V
Vss_{EXT} Negative Power Supply Voltage[1]	-3.0	-2.7	-2.4	V
I_{DD} Power Supply Current		70	350	µA
Digital Input High	2.6		5.5	V
P_{IN} Input power (50Ω): 9 kHz ≤20 MHz 20 MHz ≤6 GHz			See *fig. 28* +23	dBm dBm
T_{OP} Operating temperature range	-40	25	85	°C
Digital Input Low	0		1	V
Digital Input Leakage			15	µA

Note: 1. Applied only when external VSS power supply used. Pin 20 must be grounded when using internal Vss supply

Table 6. Absolute Maximum Ratings

Symbol	Parameter/Conditions	Min	Max	Units
V_{DD}	Power supply voltage	-0.3	6.0	V
Vss_{EXT}	Vss External Negative Power Supply Voltage (optional)	-4.0	0.3	V
V_I	Voltage on any Digital input	-0.3	5.8	V
P_{IN}	Input power (50Ω) 9 kHz ≤20 MHz 20 MHz ≤6 GHz		See *fig. 28* +23	dBm dBm
T_{ST}	Storage temperature range	-65	150	°C
V_{ESD}	ESD voltage (HBM)[1] ESD voltage (Machine Model)		500 100	V V

Note: 1. Human Body Model (HBM, MIL_STD 883 Method 3015.7)

Exceeding absolute maximum ratings may cause permanent damage. Operation should be restricted to the limits in the Operating Ranges table. Operation between operating range maximum and absolute maximum for extended periods may reduce reliability.

Figure 28. Maximum Power Handling Capability: Z_0 = 50 Ω

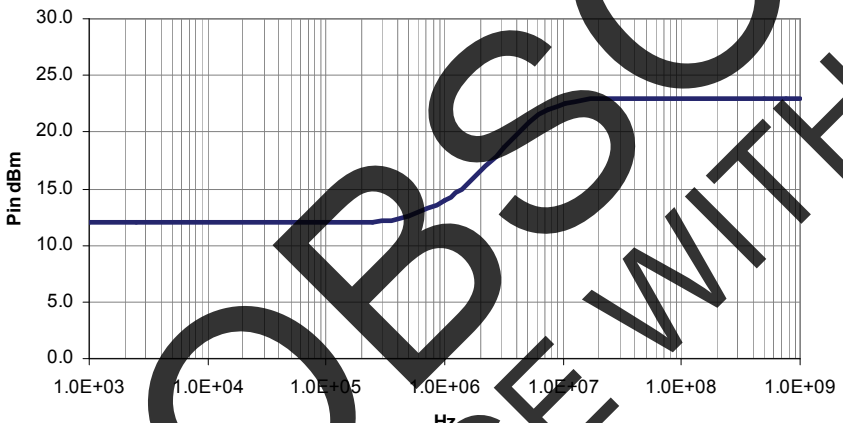


Table 7. Control Voltage

State	Bias Condition
Low	0 to +1.0 Vdc at 2 μA (typ)
High	+2.6 to +5 Vdc at 10 μA (typ)

Table 8. Latch and Clock Specifications

Latch Enable	Shift Clock	Function
0	↑	Shift Register Clocked
↑	X	Contents of shift register transferred to attenuator core

Table 9. Parallel Truth Table

Parallel Control Setting							Attenuation Setting RF1-RF2
D6	D5	D4	D3	D2	D1	D0	
L	L	L	L	L	L	L	Reference I.L.
L	L	L	L	L	L	H	0.25 dB
L	L	L	L	L	H	L	0.5 dB
L	L	L	L	H	L	L	1 dB
L	L	L	H	L	L	L	2 dB
L	L	H	L	L	L	L	4 dB
L	H	L	L	L	L	L	8 dB
H	L	L	L	L	L	L	16 dB
H	H	H	H	H	H	H	31.75 dB

Table 10. Serial Address Word Truth Table

Address Word								Address Setting
A7 (MSB)	A6	A5	A4	A3	A2	A1	A0	
X	X	X	X	X	L	L	L	000
X	X	X	X	X	L	L	H	001
X	X	X	X	X	L	H	L	010
X	X	X	X	X	L	H	H	011
X	X	X	X	X	H	L	L	100
X	X	X	X	X	H	L	H	101
X	X	X	X	X	H	H	L	110
X	X	X	X	X	H	H	H	111

Table 11. Serial Attenuation Word Truth Table

Attenuation Word								Attenuation Setting RF1-RF2
D7	D6	D5	D4	D3	D2	D1	D0 (LSB)	
L	L	L	L	L	L	L	L	Reference I.L.
L	L	L	L	L	L	L	H	0.25 dB
L	L	L	L	L	L	H	L	0.5 dB
L	L	L	L	L	H	L	L	1 dB
L	L	L	L	H	L	L	L	2 dB
L	L	L	H	L	L	L	L	4 dB
L	L	H	L	L	L	L	L	8 dB
L	H	L	L	L	L	L	L	16 dB
H	H	H	H	H	H	H	H	31.75 dB

Table 12. Serial-Addressable Register Map

Bits can either be set to logic high or logic low

D7 must be set to logic low

MSB (last in) ↓ LSB (first in) ↓

Q15	Q14	Q13	Q12	Q11	Q10	Q9	Q8	Q7	Q6	Q5	Q4	Q3	Q2	Q1	Q0
A7	A6	A5	A4	A3	A2	A1	A0	D7	D6	D5	D4	D3	D2	D1	D0

Address Word | Attenuation Word

Attenuation Word is derived directly from the attenuation value. For example, to program the 18.25 dB state at address 3:

Address word: XXXXX011
Attenuation Word: Multiply by 4 and convert to binary → 4 * 18.25 dB → 73 → 01001001
Serial Input: XXXXX01101001001

Programming Options

Parallel/Serial Selection

Either a parallel or serial-addressable interface can be used to control the PE43703. The P/S bit provides this selection, with P/S=LOW selecting the parallel interface and P/S=HIGH selecting the serial-addressable interface.

Parallel Mode Interface

The parallel interface consists of seven CMOS-compatible control lines that select the desired attenuation state, as shown in *Table 9*.

The parallel interface timing requirements are defined by *Fig. 30* (Parallel Interface Timing Diagram), *Table 9* (Parallel Interface AC Characteristics), and switching speed (*Table 1*).

For *latched*-parallel programming the Latch Enable (LE) should be held LOW while changing attenuation state control values, then pulse LE HIGH to LOW (*per Fig. 30*) to latch new attenuation state into device.

For *direct* parallel programming, the Latch Enable (LE) line should be pulled HIGH. Changing attenuation state control values will change device state to new attenuation. Direct mode is ideal for manual control of the device (using hardwire, switches, or jumpers).

Serial-Addressable Interface

The serial-addressable interface is a 16-bit serial-in, parallel-out shift register buffered by a transparent latch. The 16-bits make up two words comprised of 8-bits each. The first word is the Attenuation Word, which controls the state of the DSA. The second word is the Address Word, which is compared to the static (or programmed) logical states of the A0, A1 and A2 digital inputs. If there is an address match, the DSA changes state; otherwise its current state will remain unchanged. *Fig. 29* illustrates an example timing diagram for programming a state. It is required that all parallel control inputs be grounded when the DSA is used in serial-addressable mode.

The serial-addressable interface is controlled using three CMOS-compatible signals: Serial-In (SI), Clock (CLK), and Latch Enable (LE). The SI and CLK inputs allow data to be serially entered into the shift register. Serial data is clocked in LSB first, beginning with the Attenuation Word.

The shift register must be loaded while LE is held LOW to prevent the attenuator value from changing as data is entered. The LE input should then be toggled HIGH and brought LOW again, latching the new data into the DSA. Address Word and Attenuation Word truth tables are listed in *Table 10 & Table 11*, respectively. A programming example of the serial-addressable register is illustrated in *Table 12*. The serial-addressable timing diagram is illustrated in *Fig. 29*.

Power-up Control Settings

The PE43703 will always initialize to the maximum attenuation setting (31.75 dB) on power-up for both the serial-addressable and latched-parallel modes of operation and will remain in this setting until the user latches in the next programming word. In direct-parallel mode, the DSA can be preset to any state within the 31.75 dB range by pre-setting the parallel control pins prior to power-up. In this mode, there is a 400-µs delay between the time the DSA is powered-up to the time the desired state is set. During this power-up delay, the device attenuates to the maximum attenuation setting (31.75 dB) before defaulting to the user defined state. If the control pins are left floating in this mode during power-up, the device will default to the minimum attenuation setting (insertion loss state).

Dynamic operation between serial-addressable and parallel programming modes is possible.

If the DSA powers up in serial-addressable mode (P/S = HIGH), all the parallel control inputs DI[6:0] must be set to logic low. Prior to toggling to parallel mode, the DSA *must* be programmed serially to ensure D[7] is set to logic low.

If the DSA powers up in either latched or direct-parallel mode, all parallel pins DI[6:0] must be set to logic low prior to toggling to serial-addressable mode (P/S = HIGH), and *held* low until the DSA has been programmed serially to ensure bit D[7] is set to logic low.

The sequencing is only required once on power-up. Once completed, the DSA may be toggled between serial-addressable and parallel programming modes at will.

Figure 29. Serial-Addressable Timing Diagram

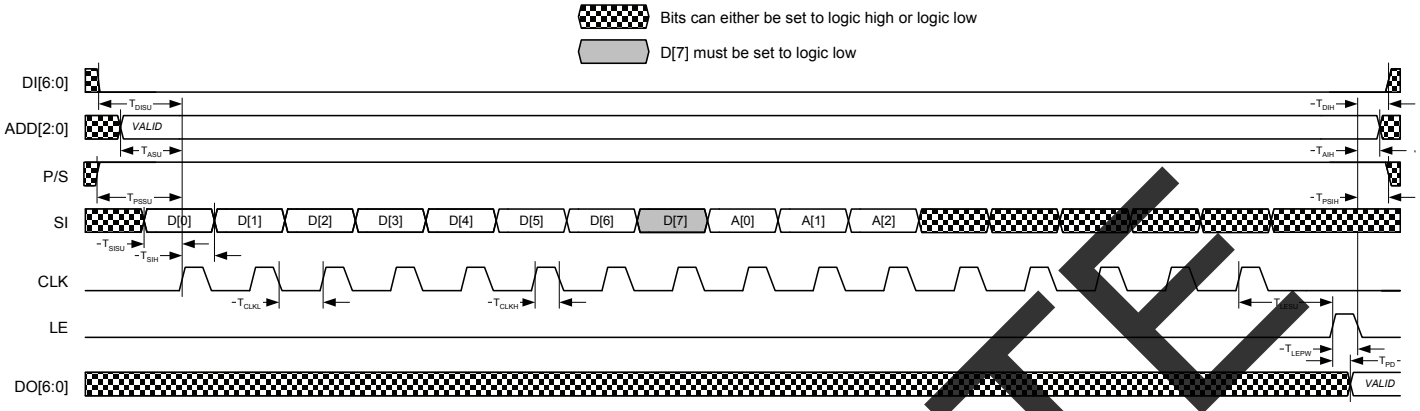


Figure 30. Latched-Parallel/Direct-Parallel Timing Diagram

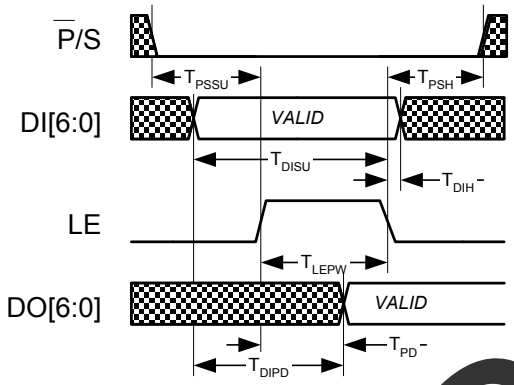


Table 13. Serial-Addressable Interface AC Characteristics

V_{DD} = 3.3 or 5.0 V, -40° C < T_A < 85° C, unless otherwise specified

Symbol	Parameter	Min	Max	Unit
F_{CLK}	Serial clock frequency		10	MHz
T_{CLKH}	Serial clock HIGH time	30		ns
T_{CLKL}	Serial clock LOW time	30	-	ns
T_{LESU}	Last serial clock rising edge setup time to Latch Enable rising edge	10	-	ns
T_{LEPW}	Latch Enable min. pulse width	30	-	ns
T_{SISU}	Serial data setup time	10	-	ns
T_{SIH}	Serial data hold time	10	-	ns
T_{DISU}	Parallel data setup time	100	-	ns
T_{DIH}	Parallel data hold time	100	-	ns
T_{ASU}	Address setup time	100	-	ns
T_{AH}	Address hold time	100	-	ns
T_{PSSU}	Parallel/Serial setup time	100	-	ns
T_{PSH}	Parallel/Serial hold time	100	-	ns
T_{PD}	Digital register delay (internal)	-	10	ns

Table 14. Parallel and Direct Interface AC Characteristics

V_{DD} = 3.3 or 5.0 V, -40° C < T_A < 85° C, unless otherwise specified

Symbol	Parameter	Min	Max	Unit
T_{LEPW}	Latch Enable minimum pulse width	30	-	ns
T_{DISU}	Parallel data setup time	100	-	ns
T_{DIH}	Parallel data hold time	100	-	ns
T_{PSSU}	Parallel/Serial setup time	100	-	ns
T_{PSIH}	Parallel/Serial hold time	100	-	ns
T_{PD}	Digital register delay (internal)	-	10	ns
T_{DIPD}	Digital register delay (internal, direct mode only)	-	5	ns

Evaluation Kit

The Digital Attenuator Evaluation Kit board was designed to ease customer evaluation of the PE43703 Digital Step Attenuator.

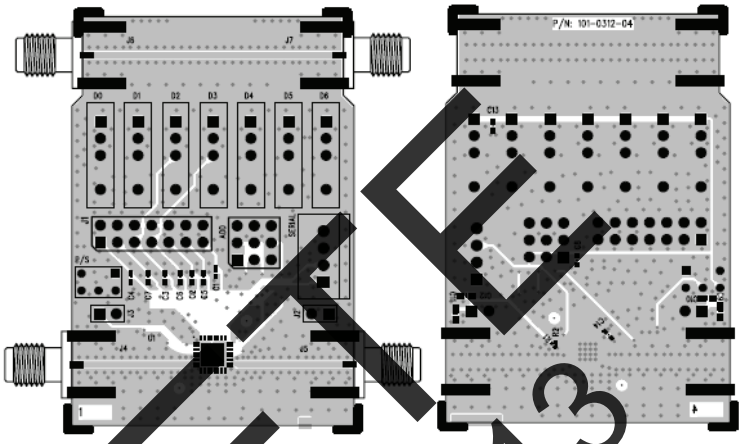
Direct-Parallel Programming Procedure
For automated direct-parallel programming, connect the test harness provided with the EVK from the parallel port of the PC to the J1 & Serial header pin and set the D0-D6 SP3T switches to the 'MIDDLE' toggle position. Position the Parallel/Serial ($\overline{P}$/S) select switch to the Parallel (or left) position. The evaluation software is written to operate the DSA in either Parallel or Serial-Addressable Mode. Ensure that the software is set to program in *Direct-Parallel* mode. Using the software, enable or disable each setting to the desired attenuation state. The software automatically programs the DSA each time an attenuation state is enabled or disabled.

For manual direct-parallel programming, disconnect the test harness provided with the EVK from the J1 and Serial header pins. Position the Parallel/Serial ($\overline{P}$/S) select switch to the Parallel (or left) position. The LE pin on the Serial header must be tied to V_{DD}. Switches D0-D6 are SP3T switches which enable the user to manually program the parallel bits. When any input D0-D6 is toggled 'UP', logic high is presented to the parallel input. When toggled 'DOWN', logic low is presented to the parallel input. Setting D0-D6 to the 'MIDDLE' toggle position presents an OPEN, which forces an on-chip logic low. Table 9 depicts the parallel programming truth table and *Fig. 30* illustrates the parallel programming timing diagram.

Latched-Parallel Programming Procedure
For automated latched-parallel programming, the procedure is identical to the direct-parallel method. The user only must ensure that *Latched-Parallel* is selected in the software.

For manual latched-parallel programming, the procedure is identical to direct-parallel except now the LE pin on the Serial header must be logic low as the parallel bits are applied. The user must then pulse LE from 0V to V_{DD} and back to 0V to latch the programming word into the DSA. LE must be logic low prior to programming the next word.

Figure 31. Evaluation Board Layout
Peregrine Specification 101-0312

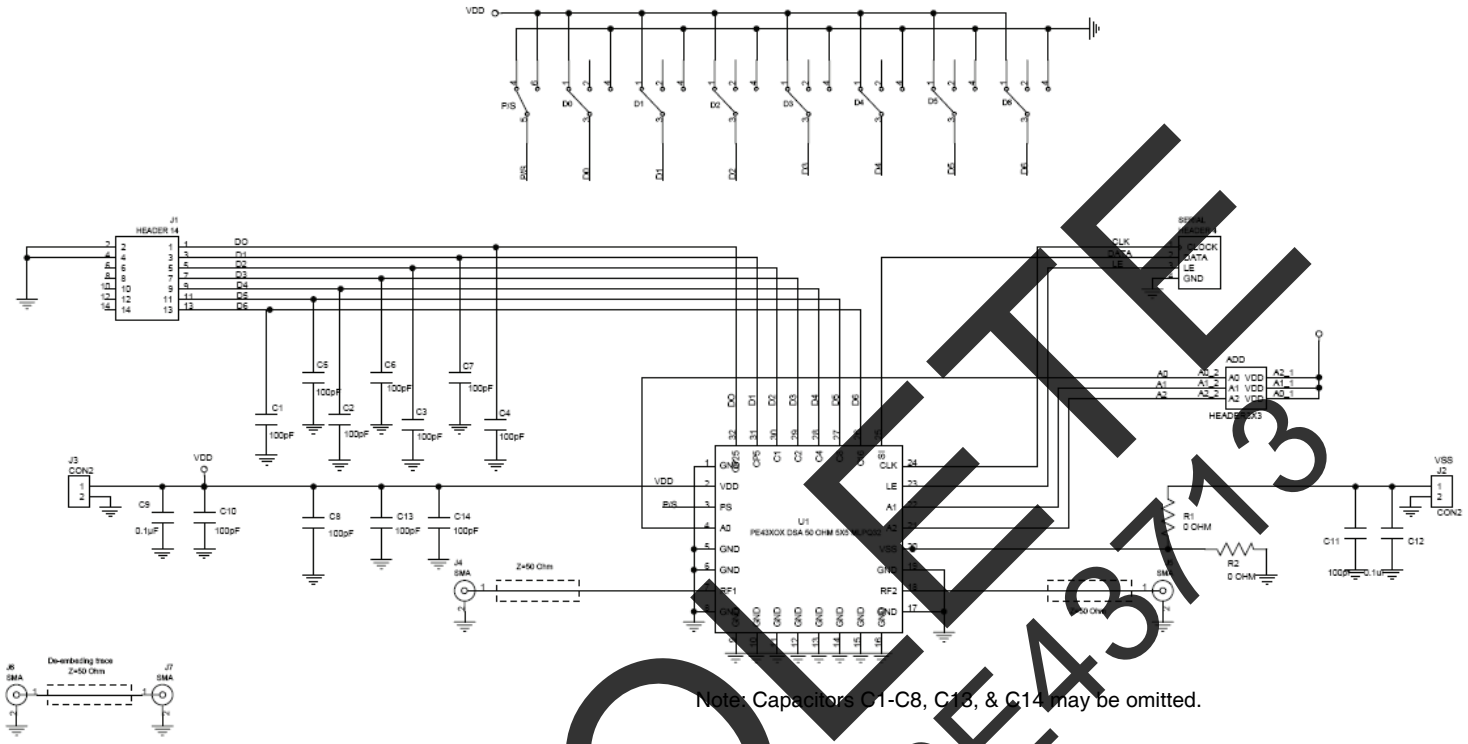


Note: Reference *Fig. 32* for Evaluation Board Schematic

Serial-Addressable Programming Procedure
Position the Parallel/Serial (P/S) select switch to the Serial (or right) position. Prior to programming, the user must define an address setting using the ADD header pin. Jump the middle pins on the ADD header A0-A2 (or lower) row of pins to set logic high, or jump the middle pins to the upper row of pins to set logic low. If the ADD pins are left open, then *000* become the default address. The evaluation software is written to operate the DSA in either Parallel or Serial-Addressable Mode. Ensure that the software is set to program in *Serial-Addressable* mode. Using the software, enable or disable each setting to the desired attenuation state. The software automatically programs the DSA each time an attenuation state is enabled or disabled.

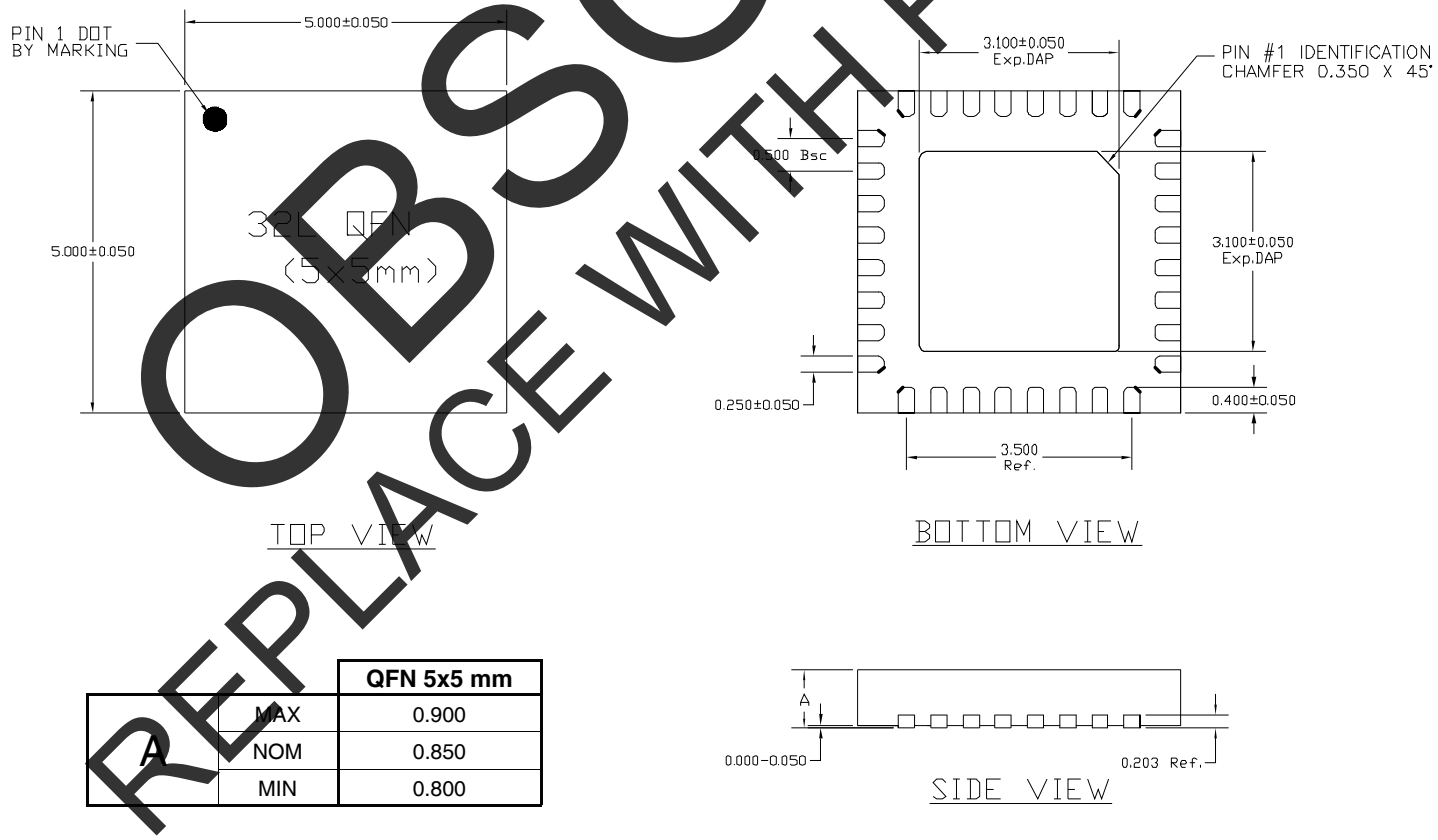
Figure 32. Evaluation Board Schematic

Peregrine Specification 102-0381



Note: Capacitors C1-C8, C13, & C14 may be omitted.

Figure 33. Package Drawing



		QFN 5x5 mm
A	MAX	0.900
	NOM	0.850
	MIN	0.800

Figure 34. Tape and Reel Drawing

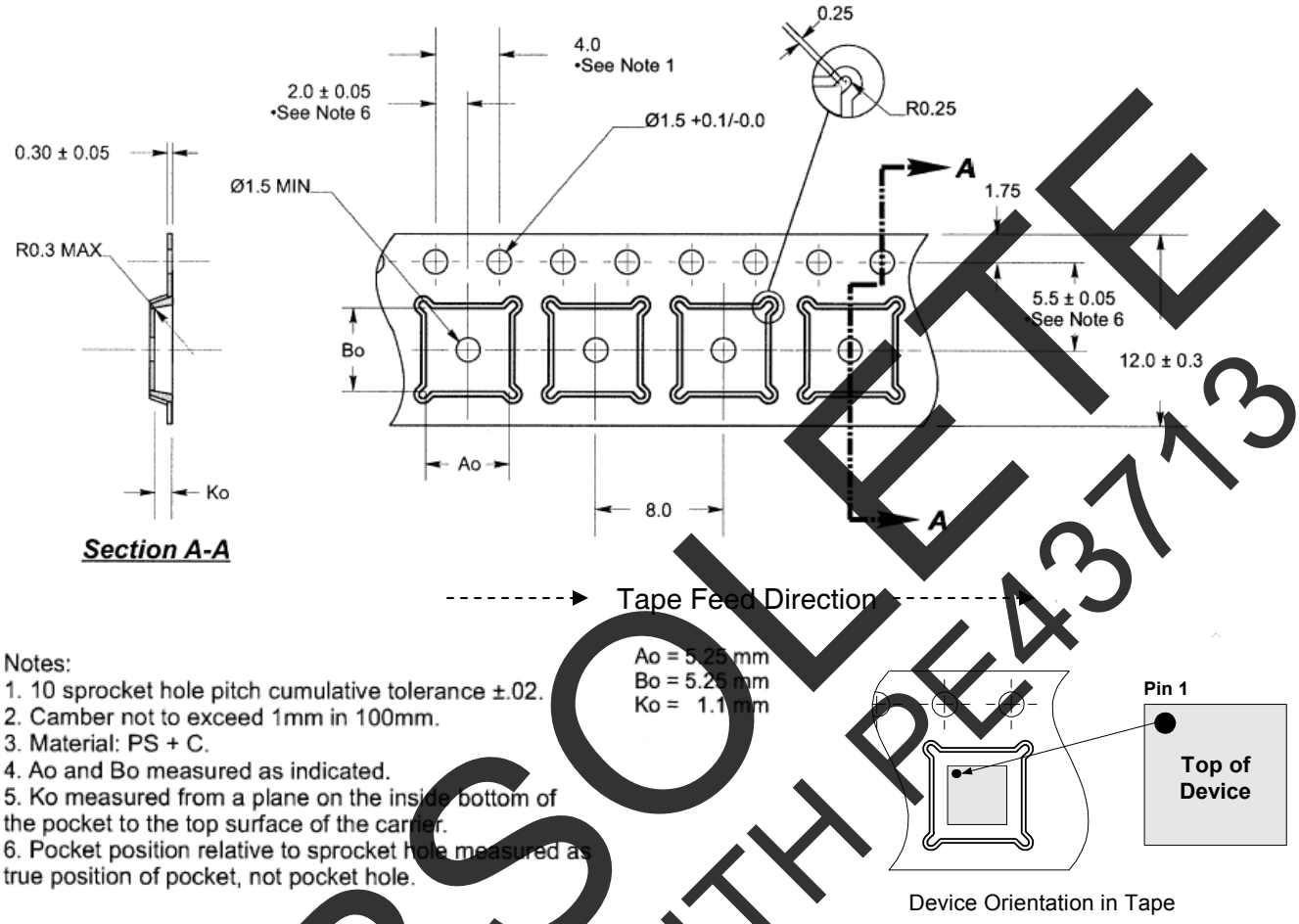
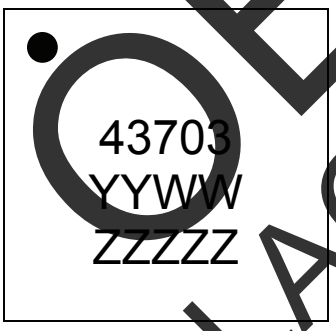


Figure 35. Marking Specifications



YYWW = Date Code
ZZZZZ = Last five digits of Lot Number

Table 15. Ordering Information

Order Code	Part Marking	Description	Package	Shipping Method
PE43703MLI	43703	PE43703 G - 32QFN 5x5mm-75A	Green 32-lead 5x5mm QFN	Bulk or tape cut from reel
PE43703MLI-Z	43703	PE43703 G – 32QFN 5x5mm-3000C	Green 32-lead 5x5mm QFN	3000 units / T&R
EK43703-01	43703	PE43703 G – 32QFN 5x5mm-EK	Evaluation Kit	1 / Box

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Data Sheet Identification

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Preliminary Specification

The data sheet contains preliminary data. Additional data may be added at a later date. Peregrine reserves the right to change specifications at any time without notice in order to supply the best possible product.

Product Specification

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